

**DESCRIPTION**

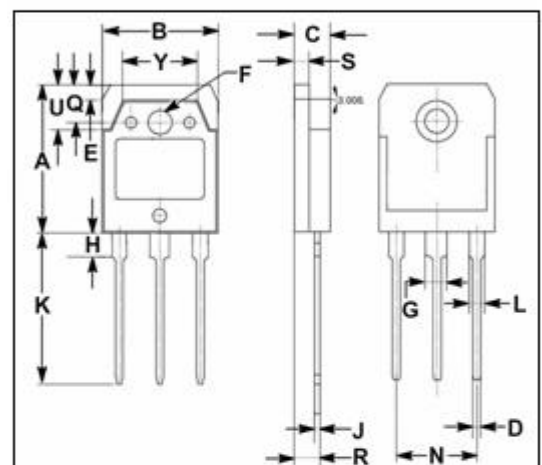
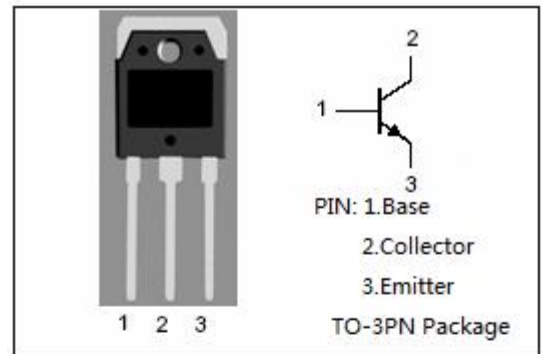
- High Collector-Emitter Breakdown Voltage-  
:  $V_{(BR)CEO} = 600V(\text{Min})$
- High Switching Speed
- High Reliability

**APPLICATIONS**

- Designed for switching regulator and general purpose applications.

**ABSOLUTE MAXIMUM RATINGS( $T_a=25^\circ\text{C}$ )**

SYMBOL	PARAMETER	VALUE	UNIT
$V_{CBO}$	Collector-Base Voltage	900	V
$V_{CEO}$	Collector-Emitter Voltage	600	V
$V_{EBO}$	Emitter-Base voltage	7	V
$I_C$	Collector Current-Continuous	14	A
$I_{CM}$	Collector Current-Peak	28	A
$I_B$	Base Current-Continuous	7	A
$P_C$	Collector Power Dissipation @ $T_C=25^\circ\text{C}$	130	W
$T_J$	Junction Temperature	150	$^\circ\text{C}$
$T_{stg}$	Storage Temperature Range	-55~150	$^\circ\text{C}$



DIM	mm	
	MIN	MAX
A	19.60	20.30
B	15.50	15.70
C	4.70	4.90
D	0.90	1.10
E	1.90	2.10
F	3.40	3.60
G	2.90	3.20
H	3.20	3.40
J	0.595	0.605
K	19.80	20.70
L	1.90	2.20
N	10.89	10.91
Q	4.90	5.10
R	3.35	3.45
S	1.995	2.100
U	5.90	6.20
Y	9.90	10.10

**ELECTRICAL CHARACTERISTICS**

$T_c=25^{\circ}\text{C}$  unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT
$V_{(BR)CEO}$	Collector-Emitter Breakdown Voltage	$I_C= 10\text{mA} ; I_B= 0$	600			V
$V_{CE(sat)}$	Collector-Emitter Saturation Voltage	$I_C= 7\text{A}; I_B= 1.4\text{A}$			0.5	V
$V_{BE(sat)}$	Base-Emitter Saturation Voltage	$I_C= 7\text{A}; I_B= 1.4\text{A}$			1.2	V
$I_{CBO}$	Collector Cutoff Current	$V_{CB}= 800\text{V} ; I_E= 0$			0.1	mA
$I_{EBO}$	Emitter Cutoff Current	$V_{EB}= 7\text{V}; I_C= 0$			0.1	mA
$h_{FE}$	DC Current Gain	$I_C= 7\text{A} ; V_{CE}= 4\text{V}$	10		25	
$C_{OB}$	Output Capacitance	$I_E= 0 ; V_{CB}= 10\text{V}; f_{test}=1.0\text{MHz}$		160		pF
$f_T$	Current-Gain—Bandwidth Product	$I_E= -1.5\text{A} ; V_{CE}= 12\text{V}$		6		MHz

Switching Times

$t_{on}$	Turn-on Time	$I_C= 7\text{A}, I_{B1}= 1.05\text{A}; I_{B2}= -3.5\text{A}$ $R_L= 35.7 \Omega ; V_{CC}= 250\text{V}$			1.0	$\mu\text{s}$
$t_{stg}$	Storage Time				5.0	$\mu\text{s}$
$t_f$	Fall Time				0.7	$\mu\text{s}$